

APTM120DA30CT1G Information


For Reference Only

Part Number [APTM120DA30CT1G](#)
Manufacturer Microsemi Corporation
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 1200V 31A SP1
Package SP1
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


APTM120DA30CT1G Specifications

Manufacturer Part Number	APTM120DA30CT1G
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	SP1
Series	POWER MOS 8?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1200V
Current - Continuous Drain (Id) @ 25°C	31A
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 2.5mA
Gate Charge (Qg) (Max) @ Vgs	560nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	14560pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	657W (Tc)
Rds On (Max) @ Id, Vgs	360 mOhm @ 25A, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Supplier Device Package	SP1
Package / Case	SP1

[Report errors?](#)

APTM120DA30CT1G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APTM120DA30CT1G Payment Methods



APTM120DA30CT1G Shipping Methods



If you have any question about APTM120DA30CT1G, please do not hesitate to contact us!

Website: <https://www.heisener.com>

E-mail: salesdept@heisener.com